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APPLICATION NO.	i i	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/577,932	77,932 05/25/2000		Shigeyuki Maruyama	000663	4823
23850	7590	11/05/2003		EXAM	INER
		ATZ, QUINTOS,	CHU, CHRIS C		
	1725 K STREET, NW SUITE 1000				PAPER NUMBER
WASHING	TON. DO	20006	2815		

DATE MAILED: 11/05/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

•		
• ,	Application No.	Applicant(s)
	09/577,932	MARUYAMA ET AL.
Office Action Summary	Examiner	Art Unit
	Chris C. Chu	2815
The MAILING DATE of this communication Period for Reply	appears on the c ver sheet	with the correspondence address
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CF after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, and If NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by such and the provided patent term adjustment. See 37 CFR 1.704(b).	DN. R 1.136(a). In no event, however, may n. a reply within the statutory minimum of the eriod will apply and will expire SIX (6) Me tatute, cause the application to become	a reply be timely filed nirty (30) days will be considered timely. DNTHS from the mailing date of this communication. ABANDONED (35 U.S.C. § 133).
1) Responsive to communication(s) filed on	<u>06 August 2003</u> .	
2a)⊠ This action is FINAL . 2b)□	This action is non-final.	
3) Since this application is in condition for all closed in accordance with the practice un	lowance except for formal m der <i>Ex parte Quayl</i> e, 1935 (atters, prosecution as to the merits is C.D. 11, 453 O.G. 213.
Disposition of Claims	- the continution	
4)⊠ Claim(s) <u>1 - 5 and 13 - 15</u> is/are pending i		
4a) Of the above claim(s) is/are with	drawn from consideration.	
5) Claim(s) 13 is/are allowed.		
6) Claim(s) 1 - 5, 14 and 15 is/are rejected.		
7) Claim(s) is/are objected to. 8) Claim(s) are subject to restriction are	nd/or election requirement	
Application Papers	nu/or election requirement.	
9) The specification is objected to by the Exan	niner.	
10) ☐ The drawing(s) filed on is/are: a) ☐ a		the Examiner.
Applicant may not request that any objection	to the drawing(s) be held in abe	yance. See 37 CFR 1.85(a).
11)☐ The proposed drawing correction filed on _	is: a)☐ approved b)☐	disapproved by the Examiner.
If approved, corrected drawings are required i	in reply to this Office action.	•
12)☐ The oath or declaration is objected to by the	e Examiner.	
Priority under 35 U.S.C. §§ 119 and 120		
13)⊠ Acknowledgment is made of a claim for for	reign priority under 35 U.S.C	. § 119(a)-(d) or (f).
a)⊠ All b)□ Some * c)□ None of:		
1. Certified copies of the priority document	nents have been received.	
2. Certified copies of the priority docum	nents have been received in	Application No
3. Copies of the certified copies of the application from the Internationa* See the attached detailed Office action for a	il Bureau (PCT Rule 17.2(a)).
14) Acknowledgment is made of a claim for dom	nestic priority under 35 U.S.0	C. § 119(e) (to a provisional application).
a) The translation of the foreign language		
Attachment(s)		
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449) Paper No. 	3) 5) Notice	w Summary (PTO-413) Paper No(s) of Informal Patent Application (PTO-152)

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DETAILED ACTION

Response to Amendment

1. Applicant's amendment filed on August 19, 2003 has been received and entered in the case.

Claim Rejections - 35 USC § 103

- 2. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 3. Claims $1 \sim 5$, 14 and 15 are rejected under 35 U.S.C. 103(a) as being unpatentable over Beddingfield in view of Matsuda et al.

Regarding claim 1, Beddingfield discloses in Figs. $2 \sim 8$ a semiconductor device comprising:

- a semiconductor element (100 and 32) having a plurality of electrodes (102 in Fig. 7 and 39 in Fig. 2);

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- a plurality of metal posts (108 and 72) each with a first shape and a first size formed on the electrode pads (104) of a redistribution layer (103), the metal posts being configured to be provided with external connection electrodes (41); and

- at least one mark member (110 and 74) with a second shape and a second size which serves as an alignment mark located in a predetermined positional relationship with the metal posts,
- wherein the mark member is made of the same material as the metal posts; and
- wherein the first shape and the first size are correspondingly different from the second shape and the second size.

Beddingfield does not disclose a redistribution layer having a plurality of electrode pads and electrical conductive patterns connecting the electrodes of the semiconductor element to the respective electrode pads. However, Matsuda et al. discloses in Fig. 1 and column 4, lines 46 ~ 52 a redistribution layer (25) having a plurality of electrode pads (31) and electrical conductive patterns (29) connecting electrodes (22) of the semiconductor element (21) to the respective electrode pads. Thus, it would have been obvious to one of ordinary skill in the art at the time when the invention was made to modify Beddingfield by using the redistribution layer as taught by Matsuda et al. The ordinary artisan would have been motivated to modify Beddingfield in the manner described above for at least the purpose of decreasing noises (column 1, lines 48 ~ 61).

Regarding claim 2, Beddingfield discloses in Figs. $2 \sim 8$ the alignment mark having an outer configuration other than a circle.

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Regarding claim 3, Beddingfield discloses in Figs. $2 \sim 8$ a width of the alignment mark measured along a plane parallel to a surface of the redistribution layer being greater than a height of the metal posts.

Regarding claim 4, Beddingfield discloses in Figs. $2 \sim 8$ a semiconductor device comprising:

- a semiconductor element (100) having a plurality of electrodes (102);
- a redistribution layer (103) including a plurality of electrode pads (108 and 72) each with a first shape and a first size located in predetermined positions of the redistribution layer; and
- at least one mark member (110 and 74) with a second shape and a second size which serves as an alignment mark located in a predetermined positional relationship with the electrode pads,
- wherein the mark member is made of the same material with the electrode pads; and
- wherein the first shape and the first size are correspondingly different from the second shape and the second size.

Beddingfield does not disclose a plurality of conductive patterns in the redistribution layer that connects the electrodes of the semiconductor device to a plurality of electrode pads. However, Matsuda et al. discloses in Fig. 1 and column 4, lines 46 ~ 52 a plurality of conductive patterns (29) in a redistribution layer (25) that connects electrodes of a semiconductor device (21) to a plurality of electrode pads (31) of the redistribution layer. Thus, it would have been obvious to one of ordinary skill in the art at the time when the invention was made to modify Beddingfield by using the plurality of conductive patterns into the redistribution layer as taught

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by Matsuda et al. The ordinary artisan would have been motivated to modify Beddingfield in the manner described above for at least the purpose of decreasing noises (column 1, lines $48 \sim 61$).

Regarding claim 5, Beddingfield discloses in Figs. $2 \sim 8$ the alignment mark having an outer configuration other than a circle.

Regarding claim 14, Beddingfield discloses in Figs. $2 \sim 8$ a semiconductor device comprising:

- a semiconductor element (100 and 32) having a plurality of electrodes (102 in Fig. 7 and 39 in Fig. 2);
- a plurality of metal posts (108 and 72) with a first shape and a first size formed on the electrode pads (104) of the redistribution layer (103), the metal posts being configured to be provided with external connection electrodes (41); and
- at least one mark member (110 and 74) with a second shape and a second size which serves as an alignment mark located in a predetermined positional relationship with the metal posts;
- wherein the first shape and the first size are correspondingly different from the second shape and the second size.

Beddingfield does not disclose a redistribution layer having a plurality of electrode pads and electrical conductive patterns connecting the electrodes of the semiconductor element to the respective electrode pads. However, Matsuda et al. discloses in Fig. 1 and column 4, lines 46 ~ 52 a redistribution layer (25) having a plurality of electrode pads (31) and electrical conductive patterns (29) connecting electrodes (22) of the semiconductor element (21) to the respective electrode pads. Thus, it would have been obvious to one of ordinary skill in the art at the time

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when the invention was made to modify Beddingfield by using the redistribution layer as taught by Matsuda et al. The ordinary artisan would have been motivated to modify Beddingfield in the manner described above for at least the purpose of decreasing noises (column 1, lines $48 \sim 61$).

Regarding claim 15, Beddingfield discloses in Figs. $2 \sim 8$ a semiconductor device comprising:

- a semiconductor element (100 and 32) having a plurality of electrodes (102 in Fig. 7 and 39 in Fig. 2);
- a plurality of metal posts (36, 108 and 72) formed on the electrode pads (104) of the redistribution layer (103); and
- at least one mark member (110 and 74) which serves as an alignment mark located in a predetermined positional relationship with the electrode part, the mark member comprising one of the metal posts but lacking the protruding electrode.

Beddingfield does not disclose a redistribution layer having a plurality of electrode pads and electrical conductive patterns connecting the electrodes of the semiconductor element to the respective electrode pads. However, Matsuda et al. discloses in Fig. 1 and column 4, lines 46 ~ 52 a redistribution layer (25) having a plurality of electrode pads (31) and electrical conductive patterns (29) connecting electrodes (22) of the semiconductor element (21) to the respective electrode pads. Thus, it would have been obvious to one of ordinary skill in the art at the time when the invention was made to modify Beddingfield by using the redistribution layer as taught by Matsuda et al. The ordinary artisan would have been motivated to modify Beddingfield in the manner described above for at least the purpose of decreasing noises (column 1, lines 48 ~ 61).

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Allowable Subject Matter

4. Claim 13 is allowed.

5. The following is an examiner's statement of reasons for allowance: the prior art of record

does not teach or suggest, either singularly or in combination, at least a plurality of suction

passages each being correspondingly connected to the plurality of concentric suction grooves and

each of the plurality of suction passages being connected to more than one hole on a porous

plate.

Any comments considered necessary by applicant must be submitted no later than the

payment of the issue fee and, to avoid processing delays, should preferably accompany the issue

fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for

Allowance."

Response to Arguments

6. Applicant's arguments with respect to claims 1, 4, 14 and 15 have been considered but are

moot in view of the new ground(s) of rejection.

Conclusion

7. Applicant's amendment necessitated the new ground(s) of rejection presented in this

Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a).

Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

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A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chris C. Chu whose telephone number is (703) 305-6194. The examiner can normally be reached on M-F (10:30 - 7:00).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

Chris C. Chu Examiner Art Unit 2815

c.c.

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